

# AOZ6232

# 0.25Ω Low-Voltage Dual-SPDT Analog Switch

# **General Description**

The AOZ6232 is a 0.25 $\Omega$  low-voltage Dual Single Pole Double Throw (SPDT) analog switch. The AOZ6232 operates from a single 1.65V to 3.3V supply. It features an ultra-low On Resistance of 0.25 $\Omega$  at a +2.7V supply and 25°C. The AOZ6232 is designed for break-before-make operation.

#### **Features**

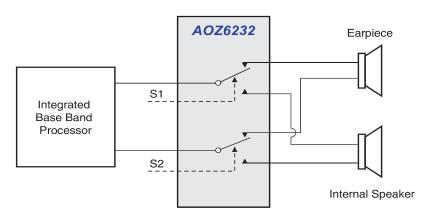
- Typical 0.25 $\Omega$  On Resistance (R<sub>ON</sub>) for +2.7V supply
- $0.15\Omega$  maximum R<sub>ON</sub> flatness for +2.7V supply
- 1.6mm x 2.1mm QFN package
- Broad V<sub>CC</sub> operating range
- Low THD (0.02% typical for  $32\Omega$  load)
- High current handling capability (350mA continuous current under 3.0V supply)

### **Applications**

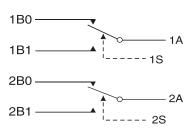
- Cell phone
- PDA
- Portable media player



### **Typical Application**



# **Pin Configuration**





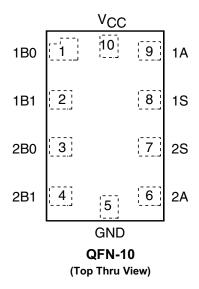
# **Ordering Information**

Part Number	Ambient Temperature Range	Package	Environmental
AOZ6232QI	-40°C to +85°C	QFN-10	RoHS Compliant
			Green Product



AOS Green Products use reduced levels of Halogens, and are also RoHS compliant. Please visit www.aosmd.com/web/quality/rohs\_compliant.jsp for additional information.

# **Pin Configuration**



# **Pin Description**

Pin Name	Function
1A, 2A, 1B0, 1B1, 2B0, 2B1	Data Ports
1S, 2S	Control Input

### **Truth Table**

Logic Input	Function
0	B0 Connected to A
1	B1 Connected to A



### **Absolute Maximum Ratings**

Exceeding the Absolute Maximum ratings may damage the device.

Symbol	Parameter	Rating
V <sub>CC</sub>	Supply Voltage	-0.5V to +3.6V
V <sub>S</sub>	Switch Voltage <sup>(1)</sup>	-0.5 to V <sub>CC</sub>
V <sub>IN</sub>	Input Voltage <sup>(1)</sup>	-0.5 to V <sub>CC</sub>
I <sub>IK</sub>	Minimum Input Diode Current <sup>(2)</sup>	-50mA
I <sub>SW</sub>	Switch Current	350mA
I <sub>SWPEAK</sub>	Peak Switch Current (Pulsed at 1ms duration, <10% Duty Cycle)	500mA
T <sub>STG</sub>	Storage Temperature Range	-65°C to +150°C
T <sub>J</sub>	Maximum Junction Temperature	+150°C
T <sub>L</sub>	Lead Temperature (Soldering, 10 seconds)	+260°C
ESD	Human Body Model	8000V
	Charged Device Model	1000V

# **Recommend Operating Ratings**

The device is not guaranteed to operate beyond the Maximum Operating Ratings.

Symbol	Parameter	Rating
V <sub>CC</sub>	Supply Voltage	1.65V to +3.3V
V <sub>IN</sub>	Control Input Voltage <sup>(3)</sup>	0V to V <sub>CC</sub>
V <sub>SW</sub>	Switch Input Voltage	0V to V <sub>CC</sub>
T <sub>A</sub>	Operating Temperature	-40°C to +85°C

#### Notes:

- 1. The input and output negative voltage ratings may be exceeded if the input and output diode current ratings are observed.
- 2. Negative current should not exceed minimum negative value.
- 3. Unused inputs must be held HIGH or LOW. They may not float.



### **DC Electrical Characteristics**

All typical values are at 25°C unless otherwise specified.

Symbol	Parameter	Conditions	V <sub>CC</sub> (V)	Min.	Тур.	Max.	Units
V <sub>IH</sub>	Input Voltage HIGH		2.7 to 3.3	1.7			V
			2.3 to 2.7	1.6			
			1.65 to 1.95	0.65 x V <sub>CC</sub>			
V <sub>IL</sub>	Input Voltage LOW		2.7 to 3.3			1.0	V
			2.3 to 2.7			0.9	
			1.65 to 1.95			0.35 x V <sub>CC</sub>	
I <sub>IN</sub>	Control Input Leakage	$V_{IN}$ = 0V to $V_{CC}$	1.65 to 3.3	-0.5		0.5	μA
	Off-Leakage Current of Port nB <sub>0</sub> and nB <sub>1</sub>	nA = 0.3V, 3.0V, nB0 or nB1 = 0.3V, 3.0V or floating	3.3	-50		50	nA
		nA = 0.3V, 2.4V, nB0 or nB1 = 0.3V, 2.4V or floating	2.7	-50		50	
		nA = 0.3V, 1.65V, nB0 or nB1 = 0.3V, 1.65V or floating	1.95	-50		50	
I <sub>A(ON)</sub>	On Leakage Current of Port 1A and 2A	nA = 0.3V, 3.0V, nB0 or nB1 = 0.3V, 3.0V or floating	3.3	-50		50	nA
		nA = 0.3V, 2.4V, nB0 or nB1 = 0.3V, 2.4V or floating	2.7	-50		50	
		nA = 0.3V, 1.65V, nB0 or nB1 = 0.3V, 1.65V or floating	1.95	-50		50	
R <sub>ON</sub>	Switch On Resistance <sup>(4)</sup> See Figure 1	I <sub>OUT</sub> = 100mA, nB0 or nB <sub>1</sub> = 0V, 0.7V, 2.0V, 2.7V	2.7		0.25	0.4	Ω
		I <sub>OUT</sub> = 100mA, nB0 or nB1 = 0V, 0.7V, 1.6V, 2.3V	2.3		0.30	0.45	
		I <sub>OUT</sub> = 100mA, nB0 or nB1 = 0.8V	1.65		0.50	0.7	
ΔR <sub>ON</sub>	On Resistance Matching	I <sub>OUT</sub> = 100mA, nB0 or	2.7		0.040	0.075	Ω
	Between Channels <sup>(5)</sup>	nB1 = 0.7V	2.3		0.040	0.080	1
			1.65		0.1		]
R <sub>FLAT(ON)</sub>	On Resistance Flatness <sup>(6)</sup>	I <sub>OUT</sub> = 100mA, nB0 or	2.7			0.15	Ω
		nB1 = 0V to V <sub>CC</sub>	2.3			0.2	]
			1.65		0.8		
I <sub>CC</sub>	Quiescent Supply Current	$V_{IN} = 0V \text{ or } V_{CC}, I_{OUT} = 0A$	3.3	-500		500	nA

#### Notes

<sup>4.</sup> On resistance is determined by the voltage drop between A and B pins at the indicated current through the switch.

<sup>5.</sup>  $\Delta R_{ON}$  =  $R_{ONmax}$  –  $R_{ONmin}$  measured at identical  $V_{CC},$  temperature, and voltage.

<sup>6.</sup> Flatness is defined as the difference between the maximum and minimum value of  $R_{\mbox{\scriptsize ON}}$  over the specified range of conditions.



# **AC Electrical Characteristics**

All typical values are at 25°C unless otherwise specified.

Symbol	Parameter	Conditions	V <sub>CC</sub> (V)	Min.	Тур.	Max.	Units
t <sub>ON</sub>	Turn-On Time	nB0 or nB1 = 1.5V, $R_L = 50Ω$ ,	2.7 to 3.3		25.0	50.0	ns
		$C_L = 35 \text{ pF}$	2.3 to 2.7		30.0	50.0	
			1.65 to 1.95		50.0	60.0	
t <sub>OFF</sub>	Turn-Off Time	nB0 or nB1 = 1.5V, $R_L = 50Ω$ ,	2.7 to 3.3		10.0	25.0	ns
		$C_L = 35pF$	2.3 to 2.7		20.0	25.0	
			1.65 to 1.95		45.0	50.0	
t <sub>BBM</sub>	Break-Before-Make Time	nB0 or nB1 = 1.5V, $R_L = 50Ω$ ,	2.7 to 3.3	2.0	17.0		ns
		$C_L = 35pF$	2.3 to 2.7	2.0	15.0		
			1.65 to 1.95	2.0	12.0		
Q	Charge Injection	$C_L = 100 pF, V_{GEN} = 0V,$ $R_{GEN} = 0\Omega$	1.65 to 3.3		9.0		pC
OIRR	Off Isolation	$f = 100kHz$ , $R_L = 50\Omega$ , $C_L = 5pF$ (Stray)	1.65 to 3.3		-95		dB
Xtalk	Crosstalk	$f = 100kHz$ , $R_L = 50\Omega$ , $C_L = 5pF$ (Stray)	1.65 to 3.3		-95		dB
BW	-3dB Bandwidth	$R_L = 50\Omega$	1.65 to 3.3		45.0		MHz
THD	Distortion $f = 20Hz \text{ to}$ $R_L = 32\Omega,$	$R_L = 32\Omega$ , $V_{IN} = 2V_{pk-pk}$ , $f = 20Hz$ to $20kHz$	2.7 to 3.3		0.024		%
		$R_L = 32\Omega$ , $V_{IN} = 1.5V_{pk-pk}$ , $f = 20Hz$ to $20kHz$	2.3 to 2.7		0.015		
		$R_L = 32\Omega$ , $V_{IN} = 1.2V_{pk-pk}$ , $f = 20Hz$ to $20kHz$	1.65 to 1.95		0.35		

# Capacitance

Symbol	Parameter	Conditions	V <sub>CC</sub> (V)	Min.	Тур.	Max.	Units
C <sub>IN</sub>	Control Pin Input Capacitance	f = 1MHz	0.0		4		pF
C <sub>OFF</sub>	B Port Off Capacitance	f = 1MHz	3.3		26		pF
C <sub>ON</sub>	A Port On Capacitance	f = 1MHz	3.3		150		pF

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# **Typical Performance Characteristics**

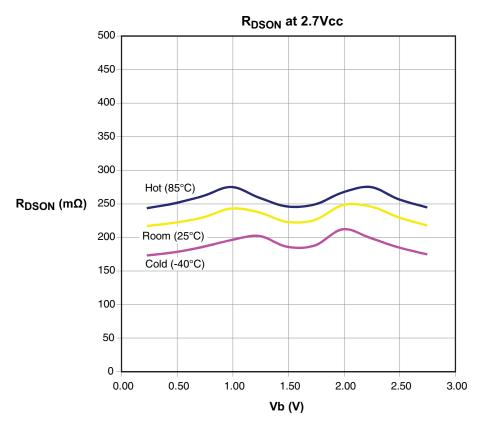


Figure 1. Switch On Resistance



# **AC Loading and Waveforms**

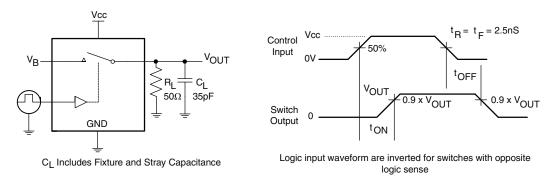


Figure 1. Turn-On/Turn-Off Timing

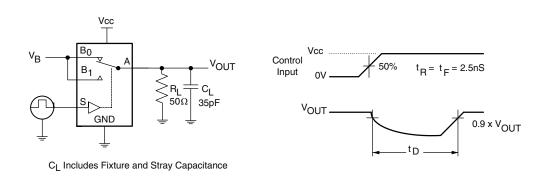


Figure 2. Break-Before-Make Timing`

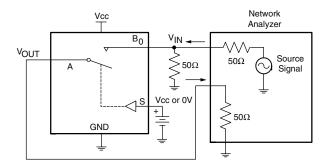


Figure 3. Off Isolation

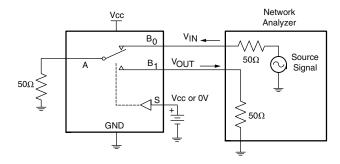


Figure 4. Crosstalk

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# AC Loading and Waveforms (continued)

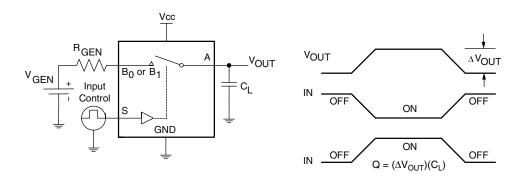


Figure 5. Charge Injection

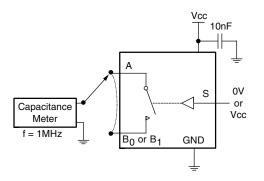


Figure 6. ON/Off Capacitance Measurement

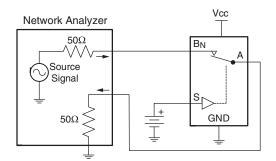


Figure 7. Bandwidth

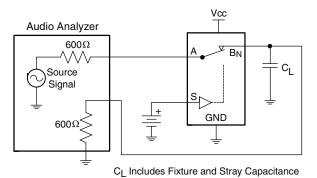
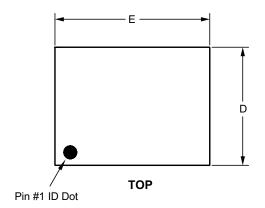


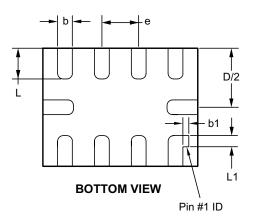
Figure 8. Harmonic Distortion

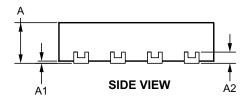
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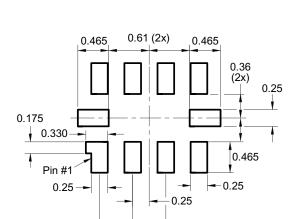


# Package Dimensions, QFN-10









0.50 (2x)

### **Dimensions in millimeters**

Symbols	Min.	Nom.	Max.		
Α	0.50	0.55	0.60		
A1	0.00	_	0.05		
A2	0	.152 REI	F		
b	0.15	0.15 0.20 0.			
b1	C	.08 REF			
D	1.55	1.60	1.65		
E	2.05	2.10	2.15		
е	(				
L	0.365	0.415	0.465		
L1	C	).15 REF			

### **Dimensions in inches**

Symbols	Min.	Nom.	Max.			
Α	0.020	0.022	0.024			
A1	0.00		0.002			
A2	0.	006 REF	=.			
b	0.006	0.008	0.010			
b1	0.	.003 REF	=.			
D	0.061	0.063	0.065			
Е	0.081	0.083	0.085			
е	0	.020 BS	3			
L	0.014	0.016	0.018			
I 1	0	006 RFF	=			

### Note:

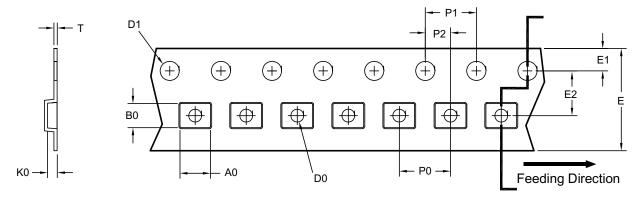
1. Controlling dimension is millimeter. Converted inch dimensions are not necessarily exact.

Unit: mm



# Tape and Reel Dimensions, QFN-10

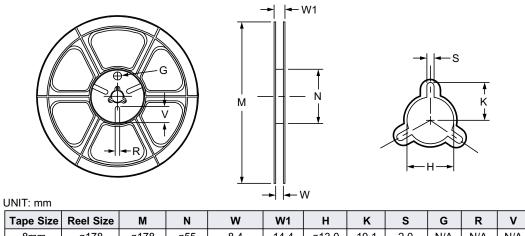
# **Carrier Tape**



UNIT: mm

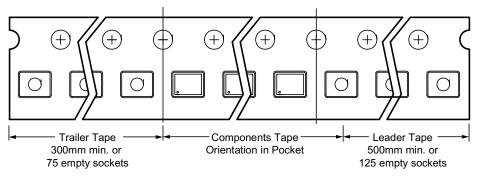
Package	A0	В0	K0	D0	D1	E	E1	E2	P0	P1	P2	Т
QFN 2.1 x 1.6	0.76	1.21	0.53	0.50	1.5	8.00	1.75	3.50	4.00	4.00	2.00	0.254
(8mm)	±0.05	±0.05	±0.05	±0.05	±0.10	+0.30/-0.10	±0.10	±0.05	±0.10	±0.10	±0.05	±0.02

### Reel



Tape Size	Reel Size	M	N	W	W1	Н	K	S	G	R	V
8mm	ø178	ø178 ±0.5	ø55 ±1	8.4 +1.5/0	14.4 Max.	ø13.0 ±0.5	10.1 Max.	2.0 ±0.5	N/A	N/A	N/A

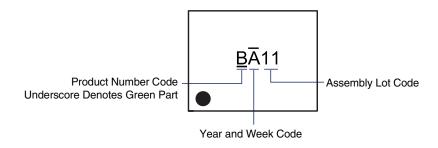
### **Leader/Trailer and Orientation**



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# **Chip Marking**



This datasheet contains preliminary data; supplementary data may be published at a later date. Alpha & Omega Semiconductor reserves the right to make changes at any time without notice.

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